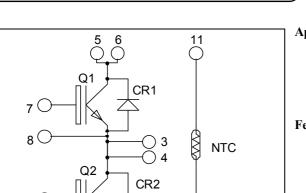
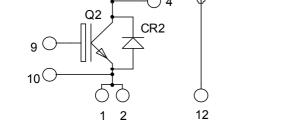
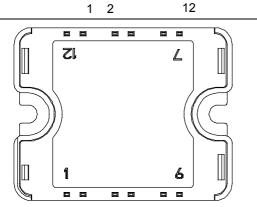


 $I_{C} = 90A$ (*a*) $Tc = 80^{\circ}C$

Phase leg NPT IGBT Power Module







Pins 1/2; 3/4; 5/6 must be shorted together

Absolute maximum ratings

Symbol Parameter Max ratings Unit V_{CES} Collector - Emitter Breakdown Voltage 600 V $T_c = 25^{\circ}C$ 110 Continuous Collector Current I_{C} $T_c = 80^{\circ}C$ 90 А Pulsed Collector Current 315 I_{CM} $T_c = 25^{\circ}C$ Gate - Emitter Voltage ±20 V V_{GE} $T_c = 25^{\circ}C$ PD Maximum Power Dissipation 416 W RBSOA Reverse Bias Safe Operating Area $T_i = 150^{\circ}C$ 200A @ 600V

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com

Application

- Welding converters
- Switched Mode Power Supplies
- Uninterruptible Power Supplies
- Motor control

Features

• Non Punch Through (NPT) Fast IGBT

 $V_{CES} = 600V$

- Low voltage drop
- Low tail current
- Switching frequency up to 100 kHz
- Soft recovery parallel diodes
- Low diode VF
- Low leakage current
- RBSOA and SCSOA rated
- Very low stray inductance
- Symmetrical design
- Internal thermistor for temperature monitoring
- High level of integration

Benefits

- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Solderable terminals both for power and signal for easy PCB mounting
- Low profile
- RoHS Compliant



All ratings (a) $T_j = 25^{\circ}C$ unless otherwise specified

Electrical Characteristics

Symbol	Characteristic	Test Conditions	Min	Тур	Max	Unit	
I _{CES}	Zero Gate Voltage Collector Current	$V_{GE} = 0V$ $T_i = 25^{\circ}C$				250	μA
		$V_{CE} = 600V$	$T_{i} = 125^{\circ}C$			500	μΛ
V _{CE(sat)}	Collector Emitter saturation Voltage	$V_{GE} = 15V$	$T_j = 25^{\circ}C$		2.0	2.5	V
		$I_C = 90A$	$T_{j} = 125^{\circ}C$		2.2		v
V _{GE(th)}	Gate Threshold Voltage	$V_{GE} = V_{CE}, I_C = 1 \text{mA}$		3		5	V
I _{GES}	Gate – Emitter Leakage Current	$V_{GE} = 20 V, V_{CE} = 0V$				±150	nA

Dynamic Characteristics

Symbol	Characteristic	Test Conditions	Min	Тур	Max	Unit	
Cies	Input Capacitance	$V_{GE} = 0V$ $V_{CE} = 25V$			4300		
Coes	Output Capacitance				470		pF
C _{res}	Reverse Transfer Capacitance	f = 1 MHz		400			
Qg	Total gate Charge	$V_{GE} = 15V$		330		nC	
Q _{ge}	Gate – Emitter Charge	$V_{Bus} = 300V$			290		
Q _{gc}	Gate – Collector Charge	$I_C = 90A$		200			
T _{d(on)}	Turn-on Delay Time	Inductive Switch		26		ns	
Tr	Rise Time	$V_{GE} = 15V$		25			
T _{d(off)}	Turn-off Delay Time	$V_{Bus} = 400V$ $I_C = 90A$		150			
T _f	Fall Time	$R_G = 5 \Omega$		30			
T _{d(on)}	Turn-on Delay Time	Inductive Switch	ing (125°C)		26		
T _r	Rise Time	$V_{GE} = 15V$			25		
T _{d(off)}	Turn-off Delay Time	$V_{Bus} = 400V$ $I_C = 90A$ $R_G = 5 \Omega$			170		ns
T _f	Fall Time				40		
Eon	Turn-on Switching Energy	$V_{GE} = 15V$ $V_{Bus} = 400V$	$T_j = 125^{\circ}C$		4.3		
E _{off}	Turn-off Switching Energy	$I_{C} = 90A$ $R_{G} = 5 \Omega$	$T_j = 125^{\circ}C$		3.5		mJ

Reverse diode ratings and characteristics

Symbol	Characteristic	Test Conditions	Min	Тур	Max	Unit	
V _{RRM}	Maximum Peak Repetitive Reverse Voltage			600			V
I _{RM}	Maximum Reverse Leakage Current	V _R =600V	$T_j = 25^{\circ}C$			35	μA
- KIVI			$T_j = 125^{\circ}C$			600	<i>p</i>
$I_{\rm F}$	DC Forward Current		$Tc = 80^{\circ}C$		60		А
	Diode Forward Voltage	$I_F = 60A$			1.8	2.2	
V _F		$I_{\rm F} = 120 {\rm A}$		2.2		V	
		$I_F = 60A$	$T_j = 125^{\circ}C$		1.5		
t _{rr}	Reverse Recovery Time	$I_{F} = 60A$ $V_{R} = 400V$ $di/dt = 400A/\mu s$	$T_j = 25^{\circ}C$		25		ns
۹ſ			$T_{j} = 125^{\circ}C$		160		115
Q _{rr}	Reverse Recovery Charge		$T_j = 25^{\circ}C$		70		nC
Vrr			$T_{j} = 125^{\circ}C$		960		пс

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Thermal and package characteristics

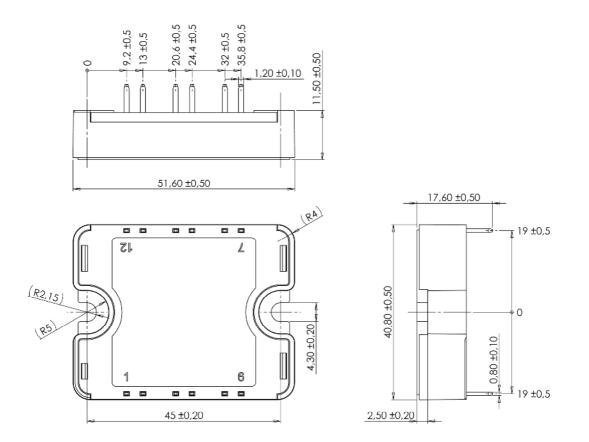
Symbol	Characteristic			Min	Тур	Max	Unit	
R _{thJC}	Junction to Case Thermal Resistance		IGB	ВТ			0.3	°C/W
K _{thJC}			Dio	de			0.65	C/ W
V _{ISOL}	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz			4000			V	
T _J	Operating junction temperature range			-40		150		
T _{STG}	Storage Temperature Range			-40		125	°C	
T _C	Operating Case Temperature						100	
Torque	Mounting torque	To heatsink		M4	2		3	N.m
Wt	Package Weight					80	g	

Temperature sensor NTC (see application note APT0406 on www.microsemi.com for more information).

Symbol	Characteristic	Min	Тур	Max	Unit
R ₂₅	Resistance @ 25°C		50		kΩ
B 25/85	$T_{25} = 298.15 \text{ K}$		3952		K

$$R_{T} = \frac{R_{25}}{\exp\left[B_{25/85}\left(\frac{1}{T_{25}} - \frac{1}{T}\right)\right]}$$
 T: Thermistor temperature
R_T: Thermistor value at T

SP1 Package outline (dimensions in mm)



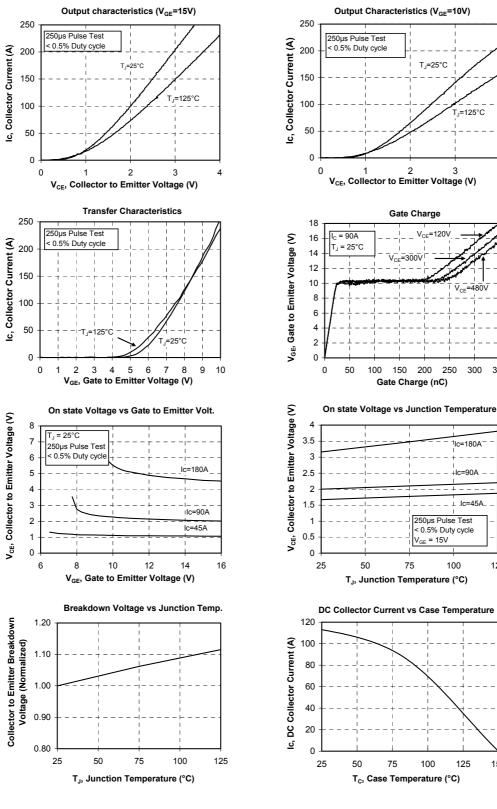
See application note 1904 - Mounting Instructions for SP1 Power Modules on www.microsemi.com

www.microsemi.com

3 - 7



Typical Performance Curve



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4

480

300 350

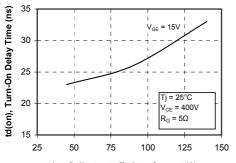
125

150

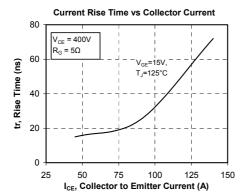
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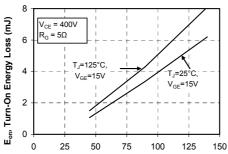
Turn-On Delay Time vs Collector Current



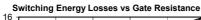


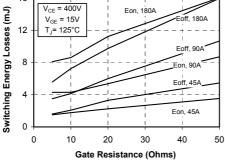


Turn-On Energy Loss vs Collector Current

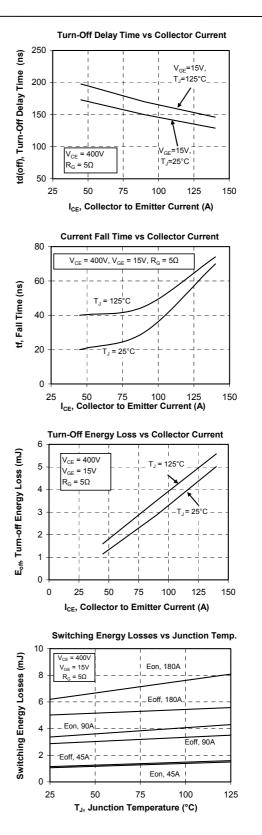






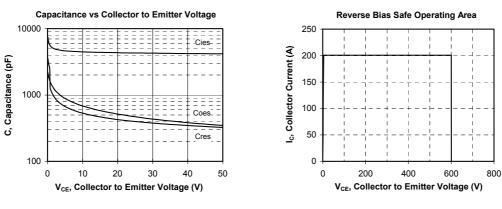


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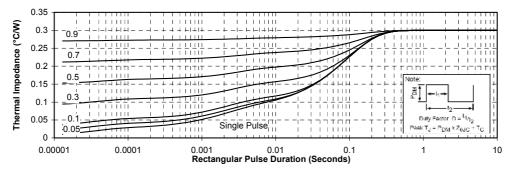


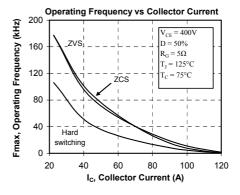
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